

Precision Ultralow Noise Microphone with Top Port and Analog Output

DESCRIPTION

The ZTS6015 is a high quality, low cost, low power analog output top-ported omni-directional MEMS microphone. ZTS6015 consists of a MEMS microphone element and an preamplifier. ZTS6015 has a high SNR and flat wideband frequency response, resulting in natural sound with high intelligibility. Extra EMI filter for RF noise attenuation is built inside. Due to the built-in filter, ZTS6015 shows high immunity to EMI.

The ZTS6015 is available in a thin 3.76mm × 2.24mm × 1.1mm surface-mount package. It is reflow solder compatible with no sensitivity degradation. The ZTS6015 is halide free.

APPLICATIONS

- Mobile telephones
- PDAs
- Digital video cameras
- Portable media devices with audio input

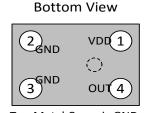
ORDERING INFORMATION

PART	RoHS	Ship, Quantity
ZTS6015	Yes	Tape and Reel, 5.2K

FEATURES

- 3.76mm×2.24mm×1.1mm surface-mount package
- Stable sensitivity over power supply range of 1.5V-3.6V
- SNR of 59dBA
- Sensitivity of -42dBV
- Low current consumption of <100μA
- Multi Chip Module (MCM) Package

Pins Configuration and Description



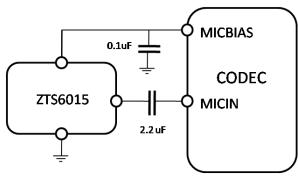
Top Metal Cover is GND.



Top Bottom Isometric Views of ZTS6015 Microphone Package

Typical Applications

The ZTS6015 output can be connected to a codec microphone input or to a high input impedance gain stage. A dc-blocking capacitor is required at the output of the microphone.



Connect to Audio Codec

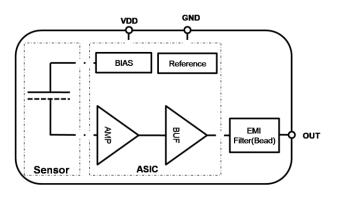


Absolute Maximum Ratings

Supply Voltage	–0.5V to +4V
Sound Pressure Level	160dB
Mechanical Shock	10000g
Vibration	Per MIL-STD-883 Method
	2007, Test Condition B
Temperature Range	40°C to +100°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Functional Block Diagram



Electro-Static Discharge Sensitivity

This integrated circuit can be damaged by ESD. It is recommended that all integrated circuits be handled with proper precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure.

Pins Description

Pin	Symbol	Description
1	VDD	Power Supply.
2,3	GND	Ground.
4	OUT	Analog output signal.

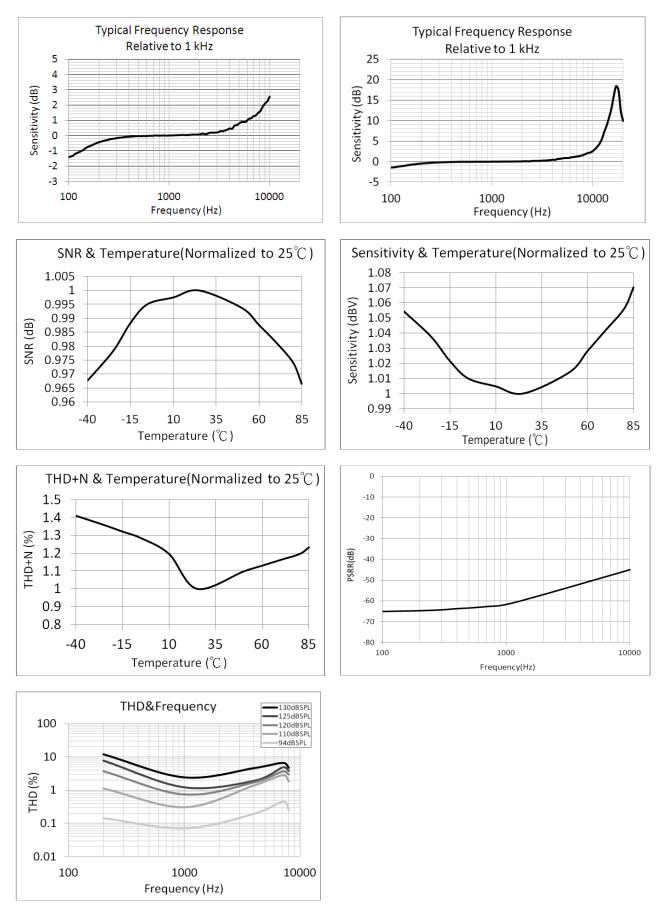


Specifications (T_A = +15°C ~+25°C, V_{DD} = +1.8V, unless otherwise noted.)

PARAMETER	Symbol	TEST CONDITIONS	MIN	ТҮР	МАХ	UNIT
Directivity				Omni		
Supply Voltage	V _{DD}		1.5		3.6	V
Current Consumption	I _{DD}	VDD=1.8V		70	100	μΑ
Sensitivity (Note)		1kHz, 94dB SPL	-45	-42	-39	dBV
Signal-to-Noise-Ratio	SNR	94dB SPL@1KHz, A-weighted		59		dBA
Equivalent Input Noise	EIN			35		dBA SPL
Total Harmonic Distortion	THD	94dB SPL @ 1KHz		0.1	0.2	%
Acoustic Overload Point	AOP	10% THD @ 1KHz		132		dBSPL
Power Supply Rejection	PSR	200mVpp sinewave @ 1KHz, VDD=1.8V		60		dB
Power Supply Rejection	PSR	100mV Vp-p, square wave @217Hz, VDD=1.8V, A-Weighted		-90		dBA
Output Impedance	Zout			200	450	Ω
Output DC Offset				0.70		V
Output Current Limit				90		μΑ
Polarity		Increasing sound pressure	Decr	easing output vo	oltage	

Note: Base on BK sound test system.

Typical Performance Characteristics





Reliability Tests

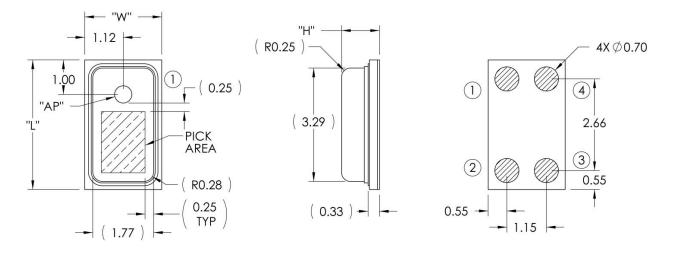
The microphone sensitivity after stress must deviate by no more than ±3dB from the initial value.

1 Hast Test. On ensting	T
1.Heat Test, Operational	Temperature: 85±3°C
	Humidity: 85±5%RH
	Duration: 12 hours
	Voltage: Applied
2.Cold Test, Operational	Temperature: -40±3°C
	Duration: 12 hours
	Voltage: Applied
3.Heat Test, Non-Operational	Temperature: 85±3°C
	Humidity: 50±5%RH
	Duration: 96 hours
	Voltage: Not Applied
4.Cold Test, Non-Operational	Temperature: -40±3°C
	Duration: 96 hours
	Voltage: Not Applied
5.Condensation Test, Non-Operational	Temperature: 25±3°C and 55±3°C
	Humidity: 95±5%RH
	Duration: 1 hours each, during 10 minutes
	ramp, 45 cycles
	Voltage: Not applied
6.Temperature Cycling, Non-Operational	Temperature: -40±3°C and 85±3°C
	Humidity: 50±5% RH
	Duration: 2 hours each, during 6 hours
	ramp, 5 cycles
	Voltage: Not applied
7.Thermal Shock Test, Non-Operational	Temperature: -40±3°C and 85±3°C
	Duration: 30 minutes each, during 5
	minutes ramp, 256 cycles
	Voltage: Not applied
8.Free Fall Test 1.5m	Placed inside test fixture and dropped on
	concrete from height 1.5m.
	(1)3 times by 6 surfaces
	(2)1 times by 12 edges
	(3)1 times by 8 corners
9.Random Vibration	Temperature: 23±5°C
	Humidity: 35~70% RH
	Duration: 2 hours each axis(X,Y,Z)
	Power Spectral Density:
	5Hz 0.10m2/s3(=1.0391*10-3g2/Hz)
	12Hz 2.20m2/s3(=22.8602*10-3g2/Hz)
	20Hz 2.20m2/s3(=22.8602*10-3g2/Hz)
	200Hz 0.04m2/s3(=0.41534*10-3g2/Hz)
	200Hz 0.04m2/s3(=0.41564*10-3g2/Hz)
10.Repeated Low Level Free Fall Test	Placed inside test fixture and dropped on
	rubber mat from height of 10cm.
	Each face 2500 times(Total 6 faces, 15000times)
11.1m Repeated Rotating	Placed inside test fixture and dropped on steel
Free Fall	sheet from height of 1.0m.
	100 times(all faces)
	Rotation speed of barrel: 10~12 falls/minute
12.Free Fall Test for master box	Corner drop: Each Corner 1 time
	Edge drop: Each Edge 1 time
	Face drop: Each Face 1 time



13.Random Vibration for master box	Sinusoidal wave vibration
	Frequency: 5~50Hz
	Acceleration:7.4m/s2(0.76G)
	Sweep speed:9Hz/min(5~50Hz, one way 5 min)
	Test duration: Direction of Face 1-3 20min
	Direction of Face 2-4 20min
	Direction of Face 5-6 20min
	Sample and direction of vibration : 1 direction
	for 1 sample
	Package on vibrating table: Free
14.Substrate bending Test	Deflection: 3mm
	Rate: 0.5mm/sec
15.Adhesion	Load: 10 N
	Duration: 10 seconds
16.Electrostatic Discharge Test	Capacitance: 150pF
	Resistance: 330Ω
	Duration: 10 times
	Air Discharge: Level 3(+/-8kV)
	Direct contact discharge: Level 1 (+/-2kV)
17.ESD-Human Body Model	3 discharges of ±2 kV direct contact to I/O pins.
	(100pF,1500Ω)
18.ESD-Charged Device Model	3 discharges of ± 500V direct contact to I/O
	pins.
19. ESD-Machine Mode	3 discharges of ±200 V direct contact to I/O
	pins.
20.Self alignment effect	Displacement: 0.15mm

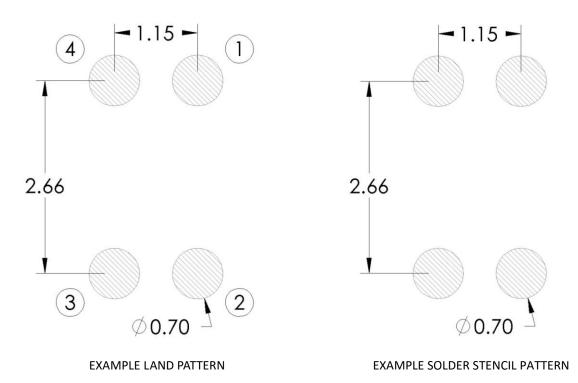
MECHANICAL SPECIFICATIOPNS



ITEM	DIMENSION	TOLERANCE	UNITS
Length (L)	3.760	±0.100	mm
Width (W)	2.240	±0.100	mm
Height (H)	1.100	±0.100	mm
Acoustic Port (AP)	Ø0.500	±0.050	mm

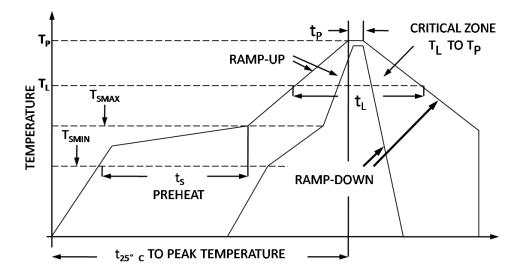
RECOMMENDED CUSTOMER LAND PATTERN

The recommended PCB land pattern for the ZTS6015 should have a 1:1 ratio to the solder pads on the microphone package. Care should be taken to avoid applying solder paste to the sound hole in PCB. The dimensions of suggested solder paste pattern refer to the land pattern which should be shrunk by 0.025 per side.



SOLDER FLOW PROFILE

The reflow profile specified in this section describes expected maximum heat exposure of components during the reflow process of NMP product PWBs. Temperature is measured on top of component. All components have to tolerate at least this profile five times (5x) without affecting electrical performance, mechanical performance or reliability.



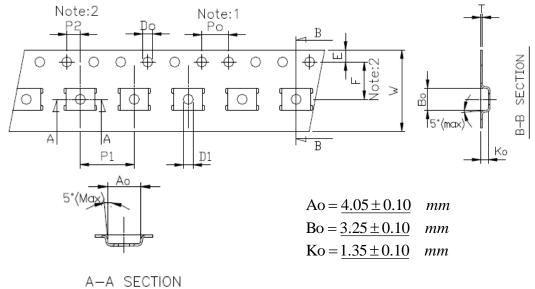
Pb-free and Sn63/Pb37 reflow profile requirements for soldering heat resistance:

Parameter		Reference	Pb-Free	Sn63/Pb37
Average Ra	mp Rate	T _L to T _P	1.25°C/sec max	1.25°C/sec max
	Minimum Temperature	T _{SMIN}	100°C	100°C
Prehear	Maximum Temperature	T _{SMAX}	200°C	150°C
	Time	T_{SMIN} to T_{SMAX}	60sec to 75sec	60sec to 75sec
Ramp-Up R	ate	T_{SMAX} to T_L	1.25°C/sec	1.25°C/sec
Time Maintained Above Liquidous		tL	50sec	60sec to 75sec
Liquidous Temperature		TL	217°C	183°C
Peak Temperature		Τ _Ρ	260°C +0°C/-5°C	215°C +3°C/-3°C
Time With Temperatur	nin +5°C of Actual Peak re	t _P	20 sec to 30 sec	20 sec to 30 sec
Ramp-Down Rate		T _{peak}	3°C/sec max	3°C/sec max
Time +2 Temperatur			5 min max	5 min max

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ZTS6015

PACKAGING



Unit : mm

Symbol	Spec.
К1	-
Po	4.0 ± 0.10
P1	8.0 ± 0.10
P2	2.0 ± 0.05
D _o	1.55 ± 0.05
D1	1.50 (MIN)
E	1.75 ± 0.10
F	5.50 ± 0.05
10P ₀	40.0 ± 0.10
W	12.0 ± 0.20
Т	0.30 ± 0.05

Notice :

1 . 10 Sprocket hole pitch cumulative tolerance is \pm 0.1mm.

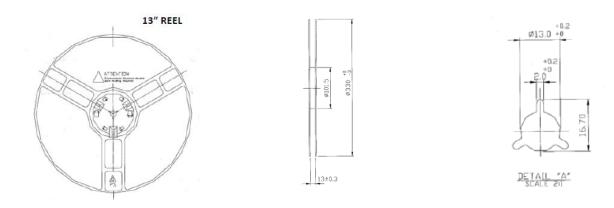
2 . Pocket position relative to sprocket hole measured as true position of pocket not pocket hole.

 $3\,$. A_0 & B_0 measured on a place 0.3mm above the bottom of the pocket to top surface of the carrier.

4 . $K_{\rm o}$ measured from a plane on the inside bottom of the pocket to the top surface of the carrier.

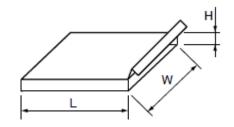
5 . Carrier camber shall be not that 1mm per 100mm through a length of 250mm.





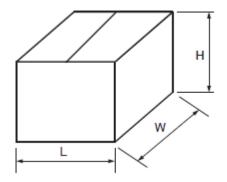
Part NO.	Reel Diameter	Quantity Per Reel	Quantity Per Inner Box	Quantity Per Outer Box
ZTS6015	13"	5,200	5,200	46,800

Dimensions for Inner Box



Unit : mm		
L	W	Н
335	339	45

Dimensions for Outer Box



Unit	:	mm

L	W	н
445	360	372

Pick and place guidelines of process



Rules of cleaning

Due to Clean the PCBA gap will make MEMS Mic. unit work improperly, please do not clean it by way of ultrasonic or use any cleaning solution to wash the soldered MEMS Mic. unit. If the PCB need to be cleaned, please seal with a tape on the both side of the acoustic hole to avoid foreign material and liquid invaded.

MEMS Mic. is a electro-acoustic component which rely on its diaphragm vibrate in response to sound pressure, so that the sound pressure can be converted to electrical signals; Base on the above, If any cleaning liquid inject the Mic. unit, the vibrate spacing of the diaphragm would be constrained. As a result of that, if the diaphragm cannot vibrate well, it will make the output signal smaller or even no output.

Rules of the pressure of vacuum nozzle

If the Vacuum nozzle pressure is much more on the metal cap, it will directly affect the displacement of the diaphragm structure. When the displacement pressure is greater than the Max input sound pressure, the diaphragm will be damaged or cracked.

Note that Vacuum nozzle pressure cannot greater than 7PSI. 1K Pa = 0.145 pounds (lb / in2) = 0.0102 KGF / CM2 = 0.0098 atm.

Rules of protection measurement

- 1 · Please do not let the vacuum nozzle suck the microphone acoustic hole.
- $2\,\cdot\,$ Do not vacuum the anti-static bag when repackaging the MEMS Mic..
- 3 · Do not blow the acoustic hole when cleaning the PCBA with air gun.

Rules of the placement of vacuum nozzle

When pick and place the Mic. unit, the SMT Vacuum Tube should be placed in the center of the left and right sides of Mic. unit and keeps 0.5mm from the edge of the acoustic hole.

This pick and place guidelines can apply to all series of ZillTek Top-Port MEMS Mic. products.



